DTB743X series

PNP -200mA -30V Digital Transistors (Bias Resistor Built-in Transistors)

Datasheet

Parameter	Value
V _{CC}	-30V
I _{C(MAX.)}	-200mA
R ₁	4.7 k Ω
R_2	10kΩ

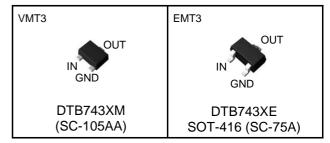
●Features

- 1) Built-In Biasing Resistors
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Complementary NPN Types :DTD743X series
- 6) Lead Free/RoHS Compliant.

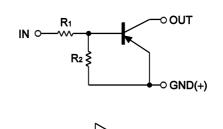
Application

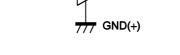
Switching circuit, Inverter circuit, Interface circuit, Driver circuit

Outline



•Inner circuit





Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
DTB743XM	VMT3	1212	T2L	180	8	8,000	M33
DTB743XE	EMT3	1616	TL	180	8	3,000	M33

● **Absolute maximum ratings** (Ta = 25°C)

Parameter	Symbol	Values	Unit
Supply voltage	V _{cc}	-30	V
Input voltage	V _{IN}	−20 to +7	V
Collector current	I _{C(MAX.)} *1	-200	mA
Power dissipation	P _D *2	150	mW
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	−55 to +150	°C

●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
lancit voltage	$V_{I(off)}$	$V_{CC} = -5V, I_{O} = -100 \mu A$	-	-	-0.3	V
Input voltage	$V_{I(on)}$	$V_0 = -0.3V, I_0 = -20mA$	-2.5	-	1	V
Output voltage	$V_{O(on)}$	$I_{O}/I_{I} = -50 \text{mA}/-2.5 \text{mA}$	-	-0.07	-0.3	V
Input current	I _I	$V_1 = -5V$	-	-	-1.4	mA
Output current	I _{O(off)}	$V_{CC} = -30V, V_1 = 0V$	-	-	-0.5	μΑ
DC current gain	G _I	$V_0 = -2V, I_0 = -100 \text{mA}$	140	-	1	-
Input resistance	R ₁	-	3.29	4.7	6.11	kΩ
Resistance ratio	R ₂ /R ₁	-	1.7	2.1	2.6	-
Transition frequency	f _T *1	$V_{CE} = -10V, I_{E} = 5mA,$ f = 100MHz	-	260		MHz

^{*1} Characteristics of built-in transistor

^{*2} Each terminal mounted on a reference footprint

●Electrical characteristic curves(Ta = 25°C)

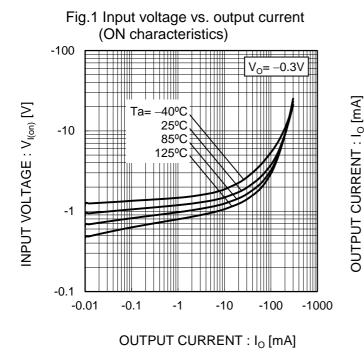


Fig.2 Output current vs. input voltage (OFF characteristics) -100 ~= -5V -10 Ta= 125°C 85°C 25°C -40°C -1 -0.1 -0.01 -0.5 -1 -1.5 INPUT VOLTAGE : $V_{I(off)}[V]$

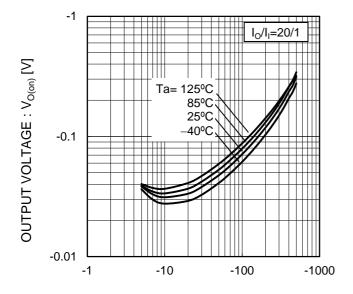
Fig.3 Output current vs. output voltage

-160 1000 Ta= 25°C $V_0 = 5V$ -1.0mA -140 -0.9mA Ta= 125°C OUTPUT CURRENT : Io [mA] 85°C -120 –0.8mA ഗ് 25°C 100 GAIN -100 -0.7mA -0.6mA -80 -0.5mA -60 CURF 10 0.4mA -40 -0.3mA -20 -0.2mA 0 0mA -0.2 -0.4 -0.6 0 -0.01 -0.1 -10 -100 -1000 OUTPUT VOLTAGE: Vo [V] OUTPUT CURRENT : Io [mA]

Fig.4 DC current gain vs. output current

●Electrical characteristic curves(Ta = 25°C)

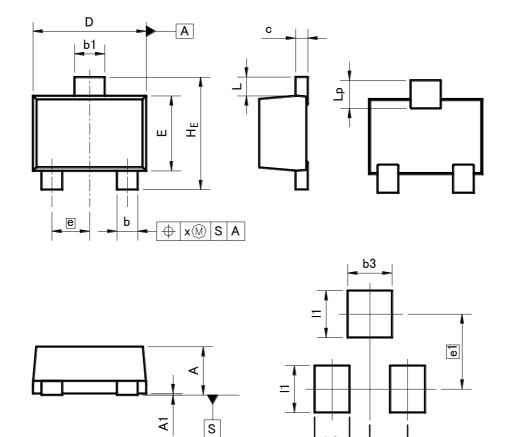
Fig.5 Output voltage vs. output current



OUTPUT CURRENT : I_O [mA]

●Dimensions (Unit:mm)

VMT3



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

b2

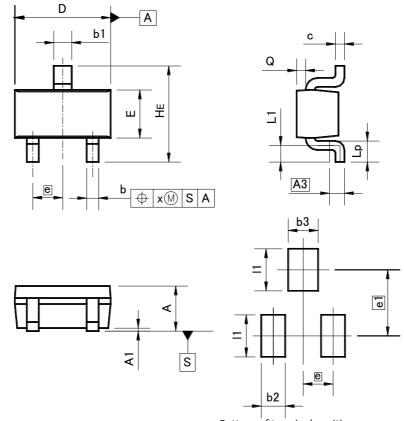
DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	0.45	0.55	0.018	0.022
A1	0.00	0.10	0.000	0.004
b	0.17	0.27	0.007	0.011
b1	0.27	0.37	0.011	0.015
С	0.08	0.18	0.003	0.007
D	1.10	1.30	0.043	0.051
E	0.70	0.90	0.028	0.035
е	0.40		0.0	02
HE	1.10	1.30	0.043	0.051
L	0.10	0.30	0.004	0.012
Lp	0.20	0.40	0.008	0.016
х	_	0.10	_	0.004

DIM	MILIMETERS		INCHES		
MIN MA		MAX	MIN	MAX	
b2	_	0.37	_	0.015	
b3	_	0.47	ı	0.019	
e1	0.80		0.0	31	
11	_	0.50	ı	0.020	

Dimension in mm / inches

●Dimensions (Unit : mm)

EMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX		
Α	0.60	0.80	0.024	0.031		
A1	0.00	0.10	0.000	0.004		
A3	0.3	25	0.0	10		
b	0.15	0.30	0.006	0.012		
b1	0.25	0.40	0.010	0.016		
С	0.10	0.20	0.004	0.008		
D	1.50	1.70	0.059	0.067		
Е	0.70	0.90	0.028	0.035		
е	0.	.50 0.02		20		
HE	1.40	1.80	0.055	0.071		
L1	0.10	1	0.004	1		
Lp	0.15		0.006	_		
Q	0.05	0.25	0.002	0.010		
х	_	0.10	_	0.004		

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
b2	- 0.40		ı	0.016
b3	- 0.50		-	0.020
e1	1.10		0.0	43
l1		0.70		0.028

Dimension in mm / inches

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